

## SALES OFFICES

### Shindengen Electric Manufacturing Co., Ltd.

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Established : August 16, 1949  
Capital : ¥17,823,148,008 (As of March 31, 2018)  
Main Business : Manufacture and sale of semiconductor products, power supply products and car electronics products  
Net Sales : ¥92,177,000,000 (FY2017)

### Sales Promotion Section, Sales Control Dept.

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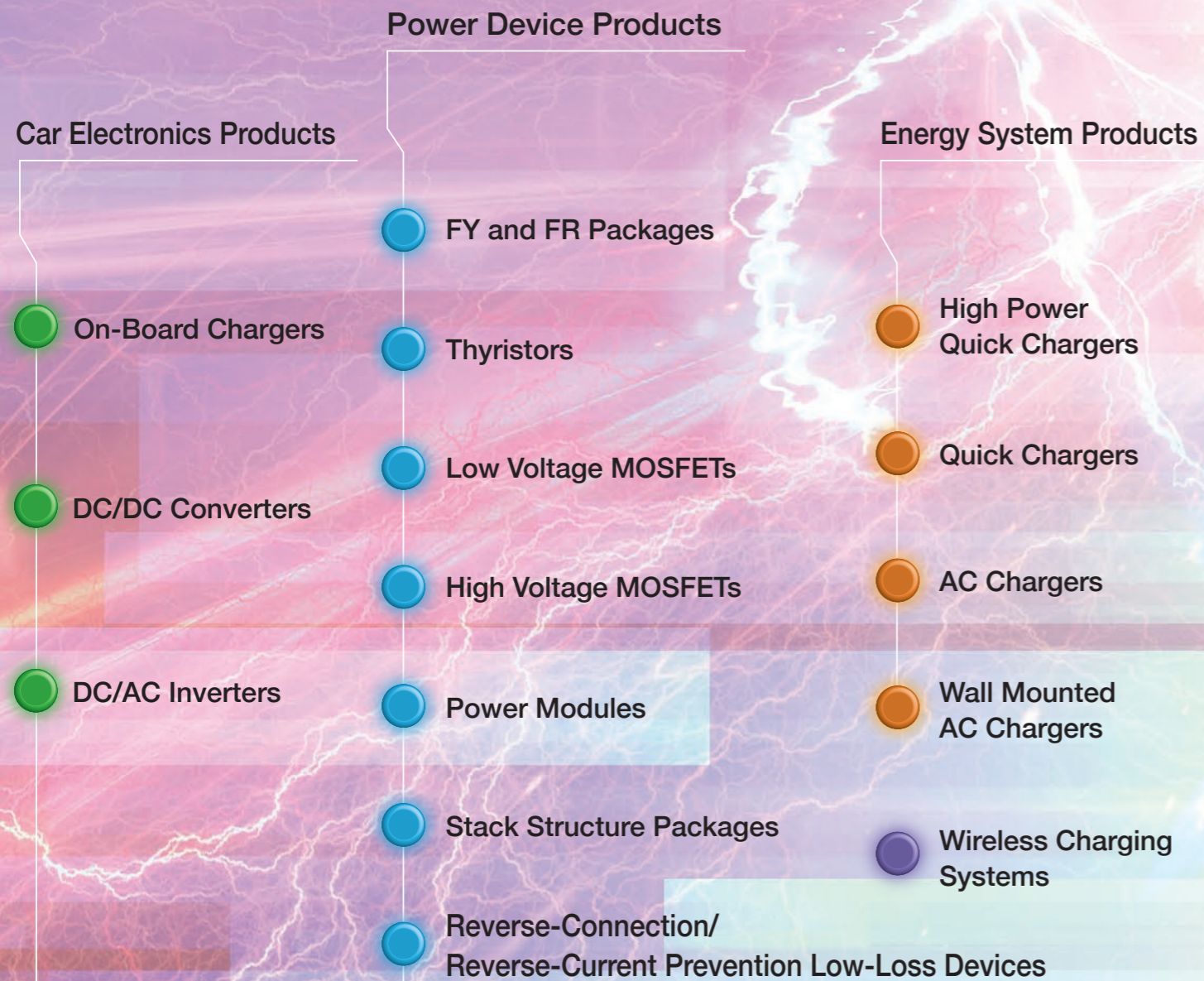
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- Printed January 2018

# 11th International Automotive Electronics Technology Exhibition



Maximizing energy conversion efficiency for the benefit of humanity and society



- Downsizing and weight saving
- High efficiency of the energy
- Realization of the low-carbon society



# Wireless Charging Systems

Wireless Charging System(WCS) Ground assembly and vehicle assembly

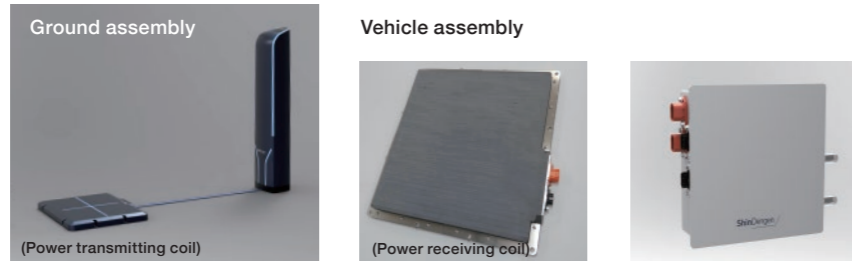


## Overview

Current EV and PHEV charging systems require a cable which faces the annoying problem of connector deterioration. The future charging system can be reliable, safe, and very convenient wireless charging. We are developing this type of system.

If the wireless charging system is installed in an electric vehicle, the electromagnetic field from the power transmitting coil on the ground delivers power to the power receiving coil in the automobile to charge the battery in the vehicle.

Even if the distance between the power transmitting coil and the power receiving coil increases, the electrical power can be transmitted with high efficiency. This system is highly robust against position misalignment and it is suitable for electric vehicles. The battery can be charged just by parking the vehicle over a power transmission coil installed at home or in a parking lot. This system provides dramatically improved convenience.



## Features

- **In the maximum class 11kW power output for passenger vehicles, we are pursuing development in vehicle height space and the industry's largest Z3 class.**
- Various safety controls conforms the industry standard
- Use of semiconductors which are produced in-house allows optimum design and improved performance.

## Specifications

- 【Ground Assembly】
- Rated input power : 7.7kVA (WPT2)/11.1kVA (WPT3)
  - Linear system/input voltage range : Single-phase 2-wire system, AC180~264V
  - Z standard : Z1, Z2, Z3 compatible
- 【Vehicle Assembly】
- Rated output power : 7.0kW/10kW
  - Output voltage : 200V~450V
  - Z standard : Z2, Z3 compatible
  - ※ Connection compatibility : Scheduled to conform to IEC 61980 (SAE J2954)



Charging

# High-output Quick Chargers for EVs



## Overview

- **New CHAdeMO version**  
CHAdeMO protocol Rev 1.2 compatible
- **High power**  
**High-power quick charger can deliver 90 kW which is about twice the power of conventional chargers. This is compatible with vehicles that have a large capacity battery**
- **Multiple outputs**  
**In addition to being able to charge two vehicles at the same time, charging time is reduced by a charging method that optimally allocates the power output.**
- **High efficiency**  
94% or more
- **Outstanding environmental resistance**  
IP54 dustproof and waterproof performance with Heavy-Duty Salt-Resistant paint
- **Lightning protection function**  
Design with strong lightning protection in compliance with IEC61000-4-5 Level-4
- **Noise**  
Use of communication-device power supply technology reduces the effects of noise on equipment installed nearby
- **Convenient functions**  
Charging condition setting function: Charging time, charging rate and usage time can be set  
Language selection function: Japanese, English and Chinese can be selected



## Specifications

- Model : SDQC2F series
- Charging standard : CHAdeMO protocol Rev 1.2
- Rated input : 3-phase 4-wire, AC415V, 50/60Hz
- Power receiving capacity : 97kVA \*1
- Power factor : 0.99 or more \*2
- Output voltage : DC150V~450V
- Output current : 0~200A(maximum per system)
- Output power : 0~90kW(maximum power of charger)
- Dimensions (W×H×D) : 990mm×1,840mm×900mm(excluding protruding parts)
- Weight : Approx. 750kg

\*1 At AC352V input, DC430V output and maximum output current  
\*2 At AC415V input, DC430V output and maximum output current



# Communication network-compatible Quick Chargers for EVs

# Communication network-compatible EV/PHEV AC Chargers

## Features

- **Built-in communication module**  
Built-in a communication module to enable provision to EV users of benefits such as authentication and payment services and charger information through smart oasis®.  
\*smart oasis® is a registered trademark of Nihon Unisys, Ltd.
- **Lightning protection function**  
Design with strong lightning protection in compliance with IEC61000-4-5 level-4
- **Noise**  
Use of communication-device power supply technology reduces the effects of noise on equipment installed nearby
- **Convenient functions**  
Charging condition setting function:  
Charging time and rate can be set  
Language selection function:  
Japanese, English and Chinese can be selected
- **Selectable output capacity \*only for 3-phase system**  
Selectable output capacity from 3 types within a range of 20 – 50kW to match the installation environment makes it possible to keep output capacity down and realize low-cost installation.



## Specifications

|                             | 【 3-phase 】  | 【 Single-phase 】            |
|-----------------------------|--|-----------------------------|
| ● Model:                    | ①SDQC-50-U ②SDQC-30-U<br>③SDQC-20-U  | SDQC-301-U                  |
| ● Charging standard:        | CHAdeMO Protocol rev.0.9 Certified   |                             |
| ● Rated input:              | 3-phase 3-wire AC200V 50/60Hz  | Single phase AC200V 50/60Hz |
| ● Power receiving capacity: | ①59kVA or lower ②36kVA ③24kVA  | 36kVA or lower*1            |
| ● Power factor:             | 95% or more  |                             |
| ● Output voltage:           | DC50V~500V   | DC50V~450V                  |
| ● Output current:           | ①0~125A ②0~75A ③0~50A  | 0~75A                       |
| ● Output power:             | ①0~50kW ②0~30kW ③0~20kW  | 0~30kW                      |
| ● Conversion efficiency:    | 90% or more  |                             |
| ● Dimensions (W x H x D):   | 550mm×1,700mm×800mm Not including protuberances  |                             |
| ● Weight:                   | ①Approx.285kg ②Approx.245kg ③Approx.225kg  | Approx.245kg                |
| ● Place of usage:           | Outdoor (waterproof performance IP33)  |                             |
| ● Ambient temperature:      | -10°C~40°C*2   |                             |
| ● Humidity:                 | 30~90%RH   |                             |
| ● Others:                   | With IC card authentication function/Communication network-compatible (U), stand-alone (not communication-compatible)<br>SDQC-(50/30/20)-S and SDQC-301-S are also available |                             |

\*1: At AC200V input, DC400V output and maximum output current  
\*2: Mounting a heater for cold regions enables use even at temperatures of 10°C or lower.  
(Option available)

Model eligible for Next Generation Vehicle Promotion Center subsidy

## Features

- **High quality, high-function power supply**  
IEC61851/1-compliant charging method JARI A0001 2014 (New JARI standard certified product)
- **Communication function**  
Connectable to smart oasis®  
\*smart oasis® is a registered trademark of Nihon Unisys, Ltd.
- **Outstanding environmental resistance**  
With IP55-compliant dustproof and waterproof performance suitable for outdoor installation (The charging connector is IP44-compliant)  
Stainless steel with outstanding anti-corrosive properties is used for the casing.
- **High maintainability**  
The front panel can be opened for ease of maintenance work.
- **Security lock**  
The charging connector is controlled automatically through interlock with user authentication.  
IC card authentication, password authentication or non-authentication may be selected for the authentication function.
- **Lightning protection function**  
Design with strong lightning protection in compliance with IEC61000-4-5 level-4



## Specifications

|  |  |
|--|--|
| ● Model:                               | PM-CS04-U-H1   |
| ● Rated voltage:                       | Single-phase AC200V 50/60Hz  |
| ● Rated continuous current:            | 20A  |
| ● Rated current during continuous use: | 18A (Charging current to the vehicle)  |
| ● Protection function:                 | Mounted with an electric leakage circuit breaker<br>*Stops supply to the vehicle when a leakage current of 15mA or more is detected.                             |
|  | <b>Overcurrent detection</b><br>*Mounted with a function that automatically stops supply to the vehicle when the current supplied to the vehicle is 20A or more. |
|  | <b>Built-in charge coupler auto lock function</b><br>*The lock is disengaged when the user is authenticated.   |
| ● Charging method:                     | Compliant with IEC61851-1, IEC61851-22, SAE J172   |
| ● Environmental conditions:            | -10°C - 45°C   |
| ● Water and dust proofing:             | Compliant with JIS C 0920 IP55 (However, the charging connector is compliant with IP44)  |
| ● Dimensions (W x H x D):              | 230mm×1,520mm×300mm (not including protuberances)  |
| ● Weight:                              | 41kg or less   |
| ● Charging connector:                  | Safety standard UL2251-compliant product, compliant with SAE J1772   |
| ● Others:                              | With IC card authentication function/Communication network-compatible (U), stand-alone (not communication-compatible)PM-CS04-S-H1 is also available.             |

Model eligible for Next Generation Vehicle Promotion Center subsidy



# Compact lightweight wall-mounted type EV/PHEV AC Chargers

# On-Board Chargers for environmentally-friendly vehicles (PHEV/EV)

Under development

## Features

- **High quality advanced power supply**  
IEC61851/1-compliant charging method JARI A0001 2014 (New JARI standard certified product)
- **Communication function**  
Communication function capable of all types of monitoring and controls via a PC.  
Capable of recording up to 2,000 items including the charging date, usage time and charged capacity and downloading log files to a PC.
- **Outstanding environmental resistance**  
IP55-compliant dustproof and waterproof performance suitable for outdoor installation (The charging connector is IP44-compliant)  
Stainless steel with outstanding anti-corrosive properties is used for the casing.
- **High maintainability**  
The front panel can be opened for ease of maintenance work.
- **Security lock**  
The charging connector is controlled automatically through interlock with user authentication.
- **Lightning protection function**  
Design with strong lightning protection in compliance with IEC61000-4-5 level-4



## Specifications

- Model: PM-CS05-S
- Rated voltage: Single-phase AC200V 50/60Hz
- Rated continuous current: 20A
- Rated current during continuous use: 18A (Charging current to the vehicle)
- Protection function: Mounted with an electric leakage circuit breaker  
\*Stops supply to the vehicle when a leakage current of 15mA or more is detected.  
Overcurrent detection  
\*Mounted with a function that automatically stops supply to the vehicle when the current supplied to the vehicle is 20A or more.  
Built-in charge coupler auto lock function  
\*The lock is disengaged when the user is authenticated.
- Charging method: IEC61851-1
- Environmental conditions: -10°C - 45°C
- Water and dust proofing: Compliant with JIS C 0920 IP55  
(However, the charging connector is compliant with IP44)
- Dimensions (W x H x D): 300mm x 655mm x 225mm (not including protuberances)
- Weight: 22kg or less
- Charging connector: Electrical Materials and Appliances Safety Act (PSE) compliant product, compliant with SAE J1772
- Lightning protection function: IEC61000-4-5 level-4 compliant
- Others: With IC card authentication function

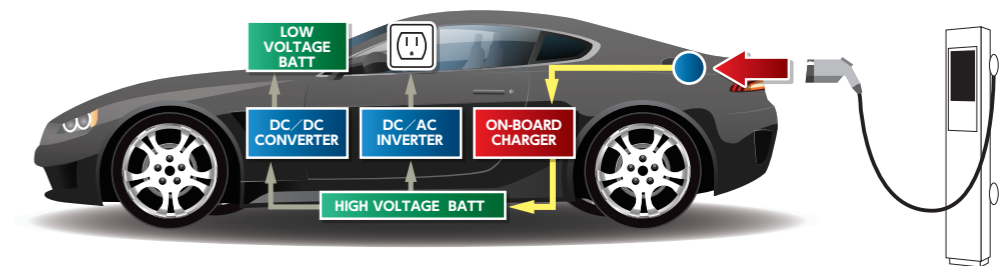
Model eligible for Next Generation Vehicle Promotion Center subsidy

## Overview

On-board charger for environmentally-friendly vehicles (EV/PHEV) is an isolated AC/DC converter that converts commercial power supply (AC100/200V) with high efficiency to charge a high voltage battery.

Environmental concerns such as global warming, air pollution and resource depletion are driving development of vehicles which have excellent environmental performance.

This product is an on-board normal charger for PHEV and EV environmentally-friendly vehicles. It converts electricity from household electrical power to charge a lithium ion or other type of high voltage battery.

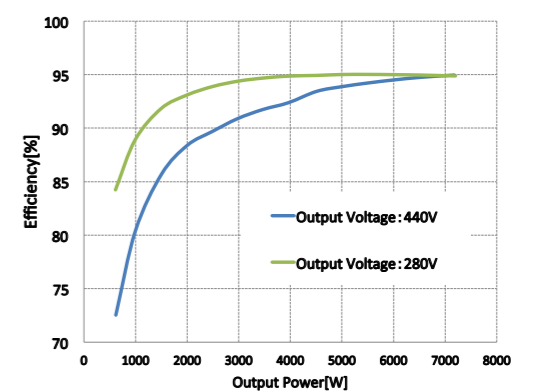


On-board charger system configuration image diagram

## Features

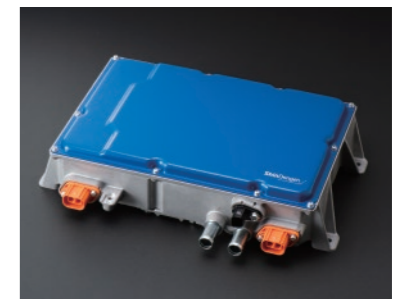
- **Compact size and high efficiency are realized by use of an interleaved bridgeless PFC circuit and LLC soft-switching circuit**
- Full digital control allows optimum power control and safe design and communication with a top class ECU
- By using semiconductors and windings which are manufactured in-house, optimum design becomes possible so that improved performance and cost reduction are realized

Efficiency characteristics (Representative)



## Specifications

- Maximum output power : 7.2kW
- Input voltage : 85~264VAC (single-phase)
- Output voltage: : DC290~410V
- Dimensions (WxDxH) : 330mm x 220mm x 82mm
- Power density : 1210W/ℓ
- Weight : 7.0kg
- Conversion efficiency : 95.0%
- Input current limit : 32A(max) variable by communication
- Cooling method : Water cooling (water temperature -40 to 65°C)
- Operation-guaranteed temperature : -40~80°C
- Mounting location : Inside and outside the vehicle



Specifications and external design are under development and subject to change without notice.



# DC/DC Converters for environmentally-friendly vehicles (EV/PHEV/HEV/FCV)

# DC/AC Inverters for environmentally-friendly vehicles (EV/PHEV/HEV/FCV)

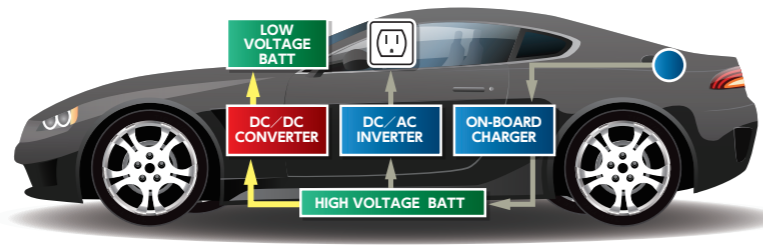
Under development

## Overview

The DC/DC converter for environmentally-friendly vehicles (HEVs, PHEV, EVs, FCVs) is an insulated type that performs highly-efficient conversion of power from high-voltage batteries (e.g. Rated voltage of 144V, 288V) to power for low-voltage batteries (12V).

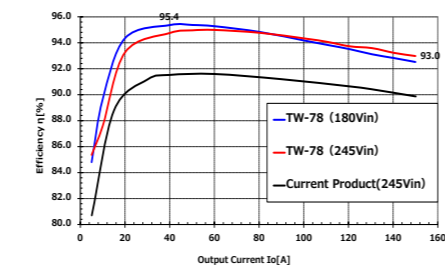
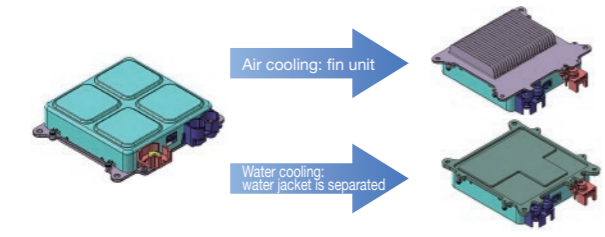
Together with advances in automotive electronics, the electrical power needed by the electrical parts is increasing. The essential parts, such as high voltage battery, inverter and motor, are also increasing so that each new generation of vehicles has higher density. As the power output capacity of the DC/DC converter increase, miniaturization and weight reduction are also demanded.

DC/DC converter system configuration image diagram



## Features

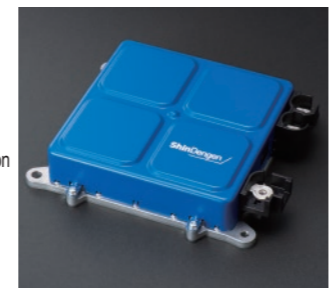
- Main circuit phase control, auxiliary power supply control, and communication control receive full-digital power supply control by one DSP in order to reduce size and cost.
- Through optimization by semiconductors and windings which are manufactured in-house, the same power output of current products can be obtained with just half the floor area.
- Industry leading maximum efficiency of 95% achieved through using a synchronous rectifier circuit
- Water cooling or air cooling can be selected by changing the case.



Efficiency representative characteristics comparison  
Vin=180,245V Vo=14.5V Ta=25°C

## Specifications

- Maximum output power : 1.9~2.7kW
- Input voltage (standard) : DC180~310V
- Input voltage (derivative specification) : Lineup setting within a range of DC90~410V (range of our lineup)
- Output voltage : DC10.0~15.5V \*Variable in 0.1V steps
- Maximum output current : 150A, 175A (Water cooling),
- Dimensions (WxHxD) : 160mmx160mmx40mm
- Power density : 2124W/ℓ
- Weight : 1.4kg
- Conversion efficiency : 94.6% (at Iout=60A)
- Control method : Full-bridge phase shift secondary synchronous rectification
- Communication system : CAN2.0 500kbps
- Cooling method : Air cooling, water cooling (non-waterproof)
- Operation-guaranteed temperature : -40 - 80°C
- Mounting location : On-board



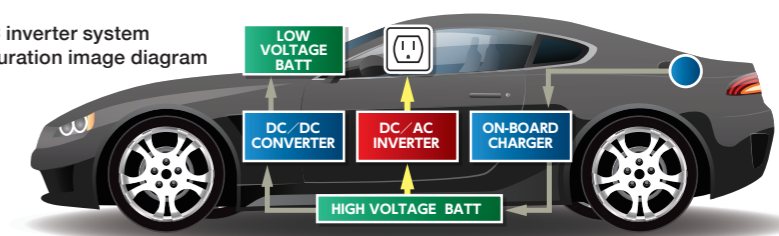
## Overview

This DC/AC inverter generates AC power from the high voltage battery in an environmentally-friendly vehicle (EV/PHEV/HEV/FCV).

As the number of vehicles with high voltage batteries increases due to market expansion of environmentally-friendly vehicles, the demand for AC power from the high voltage batteries is also increasing, for example in disaster and outdoor use.

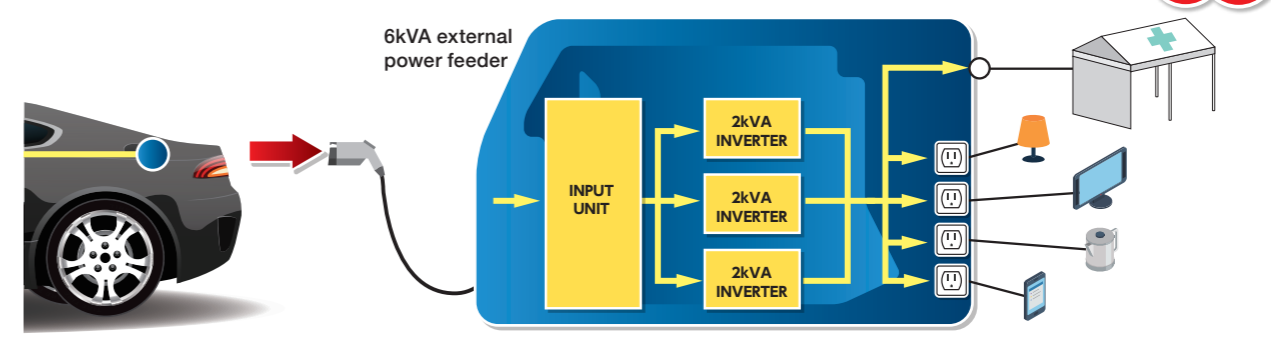
By using circuit technology from the inverter for the engine generator, an AC power supply (sine wave) with high quality and excellent overload response capability is generated from the high voltage battery.

DC/AC inverter system configuration image diagram



## Features

- With a rating of 2kVA, this can be used for loads that require excessive power at startup
- Forced air cooling from a fan is employed so the inverter can be installed in the passenger compartment or trunk.
- Parallel operation of up to 3units (6kVA) is possible, allowing expansion to external power feeders.



## Specifications

- Rated output : 2kVA
- Rated input (standard) : DC230~370V
- Output voltage : AC100/120/225V, 50/60Hz
- Output waveform distortion : 2% max (cos θ=1)
- Dimensions (WxDxH) : 190mmx213mmx86 mm
- Weight : Approx. 4.0kg
- Conversion efficiency : 90% typ. (2kVA output, cos θ=1)
- Cooling method : Forced air cooling (internal fan)
- Operation-guaranteed temperature : -30~65 °C
- Mounting location : On-board



Specifications and external design are under development and subject to change without notice.



# Low voltage 40~150V MOSFET EETMOS series

Under development

New Product

Based on AEC-Q101



## Overview

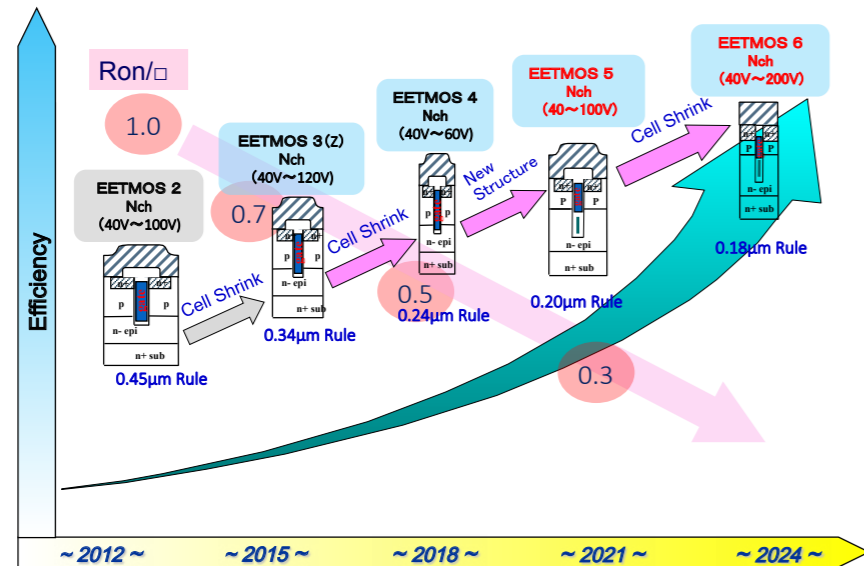
The trench gate structure and layout have been optimized and low Qg has been realized. Our lineup includes the medium voltage types which are required for the 48V applications. We can also supply bare die from custom specifications.

### 【Main Applications】

Various motor drives, DC/DC converters, LED related, various ECUs

## Features

- Wide range of breakdown voltage variations
- **Ultra low Ron (Cu clip products)**
- **Low Ron and Low Qg (industry top class) from optimum structure**



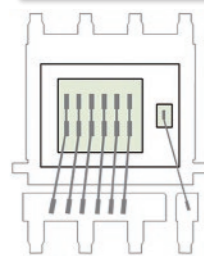
## Specifications

- LF package

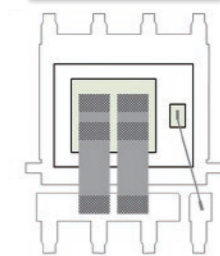
Current mainstream

Also available

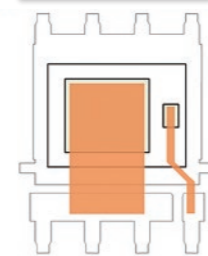
Future mainstream



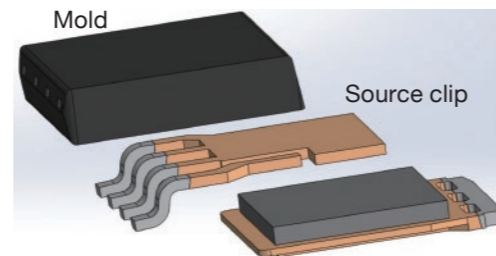
Al wire connection  
· Source: Al wire  
· Gate: Al wire



Ribbon wire connection  
· Source: Ribbon wire  
· Gate: Al wire



Cu clip connection  
· Source: Cu clip  
· Gate: Cu clip



Si die + Drain tab

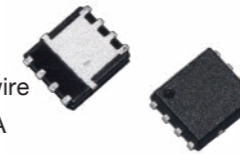
## 【LF Package products】

### Features

- 5x6mm outline (SOP8, HSON package and foot compatibility)
- Gull wing shape terminals relieve stress on the substrate
- Terminals are also plated
- Based on AEC-Q101 (Tch(max)=175°C)
- Increased current capacity (up to 140A) from copper clip connection

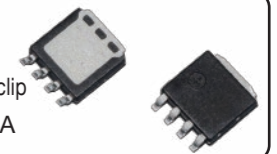
### Previos (LD package)

- 5x6 mm size
- Connection: Al wire
- ID(DC): up to 80A



### New (LF package)

- 5x6 mm size
- Connection: copper clip
- ID(DC): up to 140A



### 【Specification Example】

| Item       | V <sub>DS</sub> (min) | I <sub>D</sub> (max) | V <sub>th</sub> (typ) | Ron    |        | Ciss(typ) | Status      |
|------------|-----------------------|----------------------|-----------------------|--------|--------|-----------|-------------|
|            |                       |                      |                       | (typ)  | (max)  |           |             |
| P105LF4QNK | 40V                   | 105A                 | 3.0V                  | 1.8mΩ  | 2.3mΩ  | 3540pF    | New product |
| P140LF4QNK | 40V                   | 140A                 | 3.0V                  | 1.2mΩ  | 1.4mΩ  | 5740pF    |             |
| P64LF6QNK  | 60V                   | 64A                  | 3.0V                  | 4.0mΩ  | 5.0mΩ  | 3570pF    |             |
| P98LF6QNK  | 60V                   | 98A                  | 3.0V                  | 2.5mΩ  | 3.1mΩ  | 5780pF    |             |
| P32LF10SNK | 100V                  | 32A                  | 3.0V                  | 14.4mΩ | 18.1mΩ | 2420pF    |             |
| P50LF10SNK | 100V                  | 50A                  | 3.0V                  | 8.5mΩ  | 10.6mΩ | 4100pF    |             |
| P25LF12SNK | 120V                  | 25A                  | 3.0V                  | 21.0mΩ | 27.0mΩ | 2450pF    |             |
| P40LF12SNK | 120V                  | 40A                  | 3.0V                  | 12.5mΩ | 15.7mΩ | 4150pF    |             |

## 【FZ-7p package products】

### Features

- Improved current capacity (200A or more) by replacing source terminal connection aluminum wire with copper clip
- Based on AEC-Q101 planned(Tch(max)=175°C)

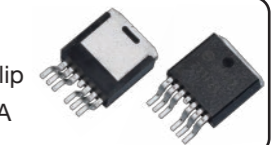
### Current products (FP package)

- TO-263Adv
- Connection: Al wire
- ID(DC): up to 180A



### New (FZ package)

- TO-263SC
- Connection: Cu clip
- ID(DC): up to 260A



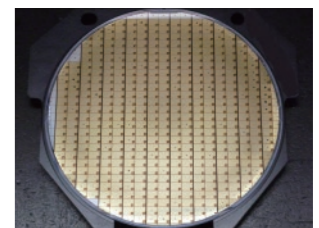
### 【Specification Example】

| Item        | V <sub>DS</sub> (min) | I <sub>D</sub> (max) | V <sub>th</sub> (typ) | Ron    |        | Ciss(typ) | Status      |
|-------------|-----------------------|----------------------|-----------------------|--------|--------|-----------|-------------|
|             |                       |                      |                       | (typ)  | (max)  |           |             |
| P240FZ4QNKA | 40V                   | 240A                 | 3.0V                  | 1.01mΩ | 1.27mΩ | 8410pF    | New product |
| P260FZ4QNKA | 40V                   | 260A                 | 3.0V                  | 0.77mΩ | 0.97mΩ | 12390pF   |             |
| P170FZ6QNKA | 60V                   | 170A                 | 3.0V                  | 1.94mΩ | 2.50mΩ | 8470pF    |             |
| P200FZ6QNKA | 60V                   | 200A                 | 3.0V                  | 1.40mΩ | 1.75mΩ | 12490pF   |             |

## 【Bare Dies】

### Features

- Double-side prober enables accurate measurement of Ron (large current 80A(max))
- Inductive load guarantee (80A(max)) and external appearance guarantee
- Breakdown voltage, chip aspect ratio, gate pad position and other individual design is possible
- Wafers and chips (trays or taping) can be supplied





# 650V superjunction MOSFET EEVAMOS series

Under development



## Overview

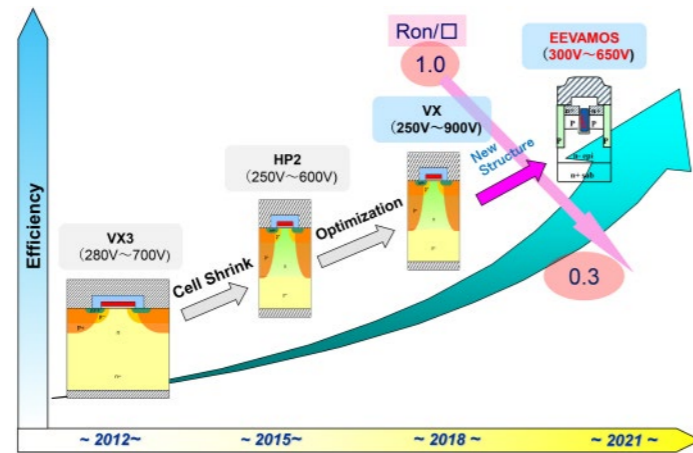
In order to achieve high efficiency, the on-resistance has been reduced to 1/4 that of our previous products (planar) and high avalanche resistance and high speed have been realized.

### 【Main Applications】

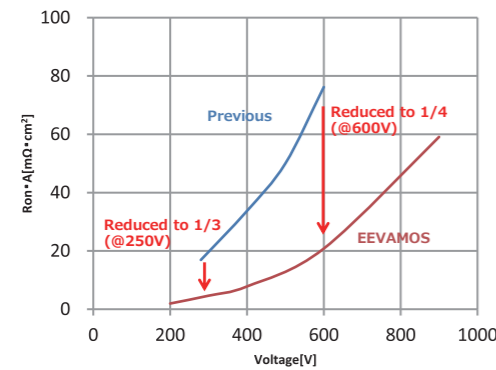
Quick chargers, DC/DC converters for EV/HEV, PFC (power factor correction) circuits

## Features

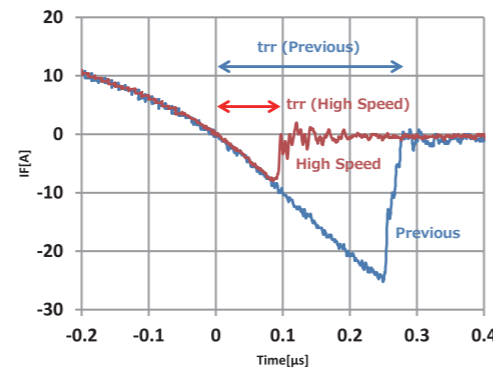
- Improved ease of use in power supply circuits thanks to a unique noise reduction method and speed up of the body diode
- Industry top level Ron and Qg



### 【Tradeoff Curve】



### 【Body diode optimization】



### 【Specification Example】

| Item       | V <sub>DS</sub> (min) | I <sub>D</sub> (max) | Ron   |       | Qg(typ) | trr(typ) | Package | Status            |
|------------|-----------------------|----------------------|-------|-------|---------|----------|---------|-------------------|
|            |                       |                      | (typ) | (max) |         |          |         |                   |
| P20F65EVFK | 650V                  | 20A                  | 0.15Ω | 0.18Ω | 40nC    | 110ns    | FTO-220 | Under development |
| P30W65EVFK | 650V                  | 30A                  | 0.09Ω | 0.11Ω | 51nC    | 130ns    | MTO-3PV | Under development |
| P60W65EVFK | 650V                  | 60A                  | 0.05Ω | 0.06Ω | 91nC    | 150ns    | MTO-3PV | Under development |

# High voltage 250~900V MOSFET VX series

Under development

New Product



## Overview

In order to achieve high efficiency, the on-resistance has been reduced 20% below that of our previous product (VX3 series). High avalanche resistance, high di/dt breakdown, and high ESD resistance have been realized.

### 【Main Applications】

Auxiliary power supplies, DC/DC converters, charging and discharging circuits

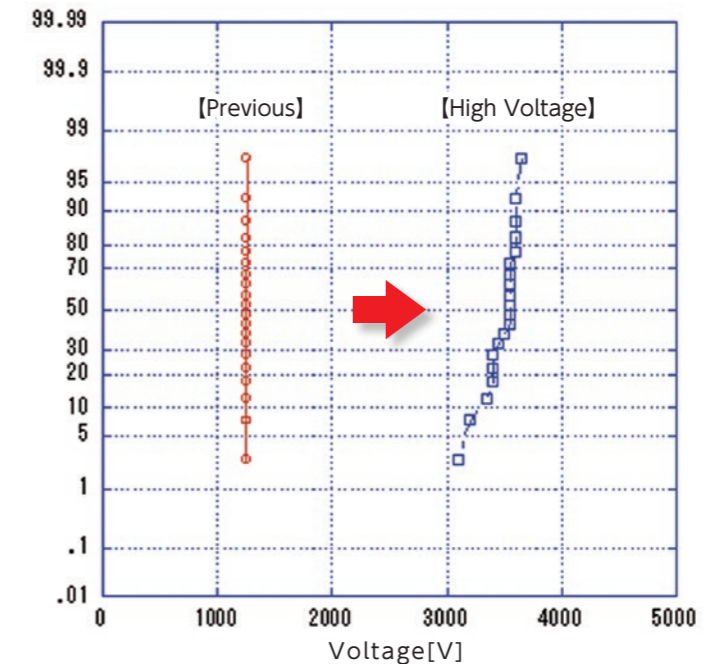
## Features

- Industry top level Ron and Qg (planar products)
- High ESD immunity (HBM: 2kV or more)
- Total avalanche guarantee
- 100% di/dt inspection (Shindengen original warranty)
- Customization such as acceleration of the body diode is acceptable



### 【ESD resistance (Human Body Model)】

Revising the chip structure greatly improved the ESD resistance (example: P1FE90VX6K).



### 【Specification Example】

| Item        | V <sub>DS</sub> (min) | I <sub>D</sub> (max) | Ron   |       | Ciss(typ) | Package   | Status            |
|-------------|-----------------------|----------------------|-------|-------|-----------|-----------|-------------------|
|             |                       |                      | (typ) | (max) |           |           |                   |
| P3FE60VX6K  | 600V                  | 3A                   | 1.85Ω | 2.31Ω | 388pF     | TO-252    | Under development |
| P16FH60VX6K | 600V                  | 16A                  | 8Ω    | 10Ω   | 2410pF    | TO-263    |                   |
| P16F60VX6K  | 600V                  | 16A                  | 0.37Ω | 0.46Ω | 1845pF    | FTO-220AG |                   |
| P1FE90VX6K  | 900V                  | 1A                   | 10.5Ω | 14Ω   | 193pF     | TO-252    | New product       |
| P5FH90VX6K  | 900V                  | 5A                   | 1.4Ω  | 2Ω    | 1400pF    | TO-263    | Under development |
| P5F90VX6K   | 900V                  | 5A                   | 1.4Ω  | 2Ω    | 1400pF    | FTO-220AG |                   |



# TO-277A (FY) Package



## Overview

For automotive applications, there were strong demands for miniaturization of diodes with  $I_F(AV) = 5A$  or more.

We have developed a device that matches the large current area, where the TO-252 or TO-263 package only could cover previously, in a compact and thin TO-277A package (in-house name: FY).

## Features

- **Thin ( $t=1.1mm$ )**
- **High heat dissipation (terminal thickness= $0.3mm$ )**
- Connection: Cu clip + solder
- Based on AEC-Q101



## Specifications

### ● Diodes

| Category                 | Item             | VRRM       | $I_F(AV)$ | $V_F(max)$ | $I_R(max)$  | Status            |             |
|--------------------------|------------------|------------|-----------|------------|-------------|-------------------|-------------|
| Ultra low $I_R$ SLSBD®   | D5FY4R5ST        | 45V        | 5A        | 0.74V      | 15 $\mu$ A  | New product       |             |
|                          | D10FY4R5ST       | 45V        | 10A       | 0.74V      | 30 $\mu$ A  |                   |             |
|                          | D15FY4R5ST       | 45V        | 15A       | 0.74V      | 40 $\mu$ A  |                   |             |
|                          | D5FY6ST          | 60V        | 5A        | 0.78V      | 15 $\mu$ A  |                   |             |
|                          | D10FY6ST         | 60V        | 10A       | 0.78V      | 30 $\mu$ A  |                   |             |
|                          | D15FY6ST         | 60V        | 15A       | 0.78V      | 40 $\mu$ A  |                   |             |
|                          | D5FY10ST         | 100V       | 5A        | 0.86V      | 15 $\mu$ A  |                   |             |
|                          | D10FY10ST        | 100V       | 10A       | 0.86V      | 30 $\mu$ A  |                   |             |
|                          | D15FY10ST        | 100V       | 15A       | 0.86V      | 40 $\mu$ A  |                   |             |
|                          | D5FY15ST         | 150V       | 5A        | 0.88V      | 15 $\mu$ A  |                   |             |
|                          | D10FY15ST        | 150V       | 10A       | 0.88V      | 30 $\mu$ A  |                   |             |
|                          | D15FY15ST        | 150V       | 15A       | 0.88V      | 40 $\mu$ A  |                   |             |
|                          | Low $I_R$ SLSBD® | D5FY4R5SY  | 45V       | 5A         | 0.59V       |                   | 200 $\mu$ A |
|                          |                  | D10FY4R5SY | 45V       | 10A        | 0.59V       |                   | 400 $\mu$ A |
| D15FY4R5SY               |                  | 45V        | 15A       | 0.59V      | 500 $\mu$ A |                   |             |
| D5FY6SY                  |                  | 60V        | 5A        | 0.67V      | 200 $\mu$ A |                   |             |
| D10FY6SY                 |                  | 60V        | 10A       | 0.67V      | 400 $\mu$ A |                   |             |
| D15FY6SY                 |                  | 60V        | 15A       | 0.67V      | 500 $\mu$ A |                   |             |
| D5FY10SY                 |                  | 100V       | 5A        | 0.8V       | 200 $\mu$ A |                   |             |
| D10FY10SY                |                  | 100V       | 10A       | 0.8V       | 400 $\mu$ A |                   |             |
| General rectifying diode | D10FY60VE        | 600V       | 10A       | 1.00V      | 10 $\mu$ A  | Under development |             |
|                          | FRD              | D5FY60K    | 600V      | 5A         | 1.50V       |                   | 10 $\mu$ A  |

### ● TVS (Power Zener) Features: High withstand capacity 2000W (10/1000 $\mu$ s)

| Category | Item      | $V_R$ | $V_{BR}$ | PRSM  | $I_R(max)$ | Status            |
|----------|-----------|-------|----------|-------|------------|-------------------|
| TVS      | ST20-27FY | 23V   | 25~29V   | 2000W | 5 $\mu$ A  | Under development |
|          | ST20-30FY | 24V   | 28~32V   | 2000W | 5 $\mu$ A  |                   |
|          | ST20-33FY | 25V   | 31~35V   | 2000W | 5 $\mu$ A  |                   |
|          | ST20-36FY | 25V   | 34~38V   | 2000W | 5 $\mu$ A  |                   |

# FR Package

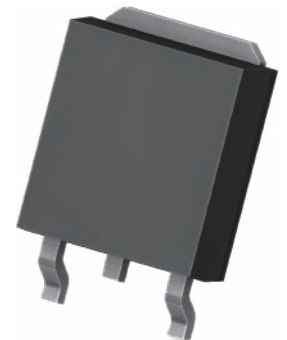


## Overview

In a size equivalent to TO-252, this package realizes a large current area that was impossible under the previous various constraints.

## Features

- **Thin ( $t=2.3mm$ ) (TO-252 is around 2.6mm)**
- Can be mounted on TO-252 standard soldering pads
- Connection: Cu clip + solder



## Specifications

### ● Diodes

| Category                 | Item      | VRRM | $I_F(AV)$ | $V_F(max)$ | $I_R(max)$   | Status            |
|--------------------------|-----------|------|-----------|------------|--------------|-------------------|
| General rectifying diode | D10FR60V  | 600V | 10A       | 1.05V      | 10 $\mu$ A   | New product       |
|                          | D15FR60V  | 600V | 15A       | 1.05V      | 10 $\mu$ A   |                   |
| Ultra low $I_R$ SLSBD®   | D15FR4ST  | 40V  | 15A       | 0.74V      | 40 $\mu$ A   |                   |
|                          | D20FR4ST  | 40V  | 20A       | 0.74V      | 60 $\mu$ A   |                   |
| Low $V_F$ SBD            | D20FR4R5S | 45V  | 20A       | 0.55V      | 2800 $\mu$ A | Under development |
| Ultra high speed FRD     | D10FR60LA | 600V | 10A       | 2.1V       | 10 $\mu$ A   |                   |
|                          | D15FR60LA | 600V | 15A       | 2.1V       | 10 $\mu$ A   |                   |



# Thyristors



## Overview

〈FR Package〉  
Includes a 12A rated chip in a size which is equivalent to the previous TO-252 which was about 5A.

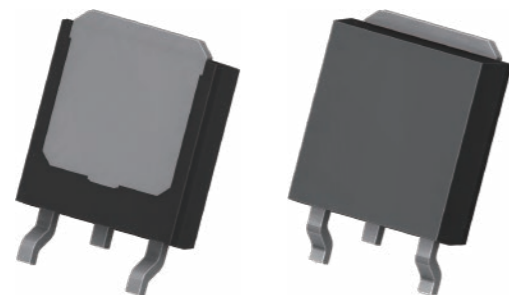
〈JA Package〉  
A thyristor and a bridge diode are modularized in our bridge diode package (JA) which realizes space saving and high efficiency.

## Features

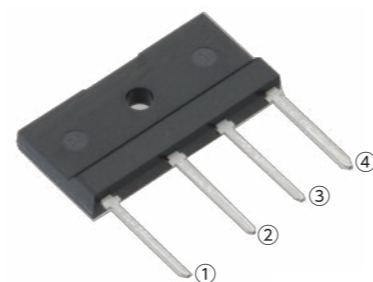
- Miniaturization, thin form, large current
- High heat dissipation

## Specifications

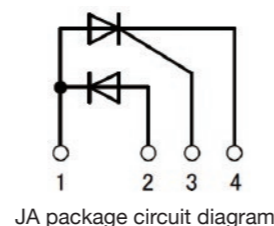
| Item      | Tj    | V <sub>DRM</sub> | V <sub>RRM</sub> | I <sub>T(AV)</sub> | I <sub>GT</sub> | Externals | Status            |
|-----------|-------|------------------|------------------|--------------------|-----------------|-----------|-------------------|
| KC8FR40H  | 125°C | 400V             | 400V             | 8A                 | 0.2mA           | FR        | Under development |
| KC12FR40  | 125°C | 400V             | 400V             | 12A                | 10mA            |           |                   |
| KR12JA40A | 125°C | 400V             | 400V             | 12A                | 10mA            | JA        | New product       |



FR package  
(similar to TO-252)



JA package



JA package circuit diagram

# Power Modules (Standard package)

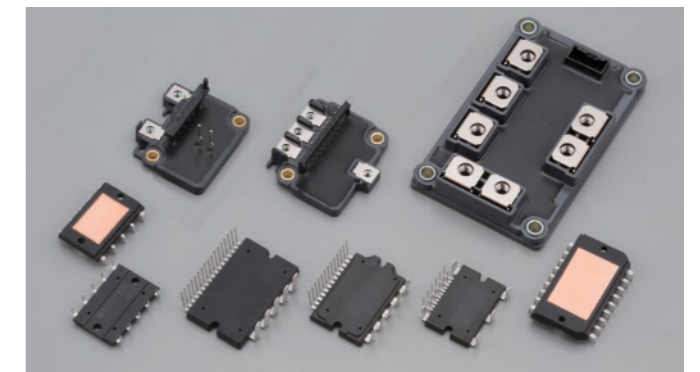


## Overview

Starting with an industrial motor-oriented power module in 2014, we have mass-produced modules for automotive use, DC/DC converters, EPS, and EOP. In order to respond to the needs of compact and lightweight in-vehicle devices, we will launch a series of “standard packages” that incorporate high heat dissipation packaging technology.

## Features

- Wide range of standard packages
- Semi-custom or full-custom can be accommodated at your request



|                           | MG031   | MG035  | MG032  |
|---------------------------|---|--|--|
| Outline                   |   |  |  |
| Circuit diagram (example) |   |  |  |
| Insulated/non-insulated   | Non-insulated   | Insulated  | Insulated  |
| Characteristics (example) | V <sub>DSS</sub> =40V<br>R <sub>Ds(ON)typ</sub> =1.75mΩ<br>I <sub>D</sub> =148A | V <sub>DSS</sub> =40V<br>R <sub>Ds(ON)typ</sub> =1.9mΩ<br>I <sub>D</sub> =160A | V <sub>DSS</sub> =100V<br>R <sub>Ds(ON)typ</sub> =0.99mΩ<br>I <sub>D</sub> =420A |
| Status                    | New product   | Under development  | New product  |



# Power Modules (Next generation devices)



## Overview

In recent years, next generation devices (SiC and GaN) that do not use silicon are attracting attention due to their value in power supply miniaturization and high efficiency. Although next-generation devices can realize high efficiency by reducing switching loss, there was a problem in mastering their usage because of the high slew rate. To solve this, we modularized the basic circuit to make it easy to handle and easy to realize miniaturization and high efficiency in the final equipment.

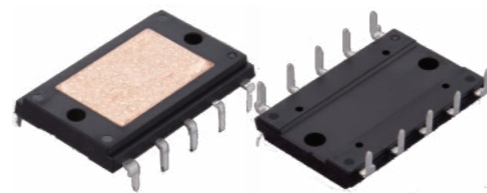
## Features

### SiC Power Modules

- Realization of miniaturization and large capacity by use of an insulating package with high heat dissipation
- The totem-pole bridgeless PFC incorporates our proprietary low VF diodes

### GaN Power Modules

- **Easy handling is achieved by making the half-bridge a single module**
- Realization of miniaturization and large capacity by use of an insulating package with high heat dissipation



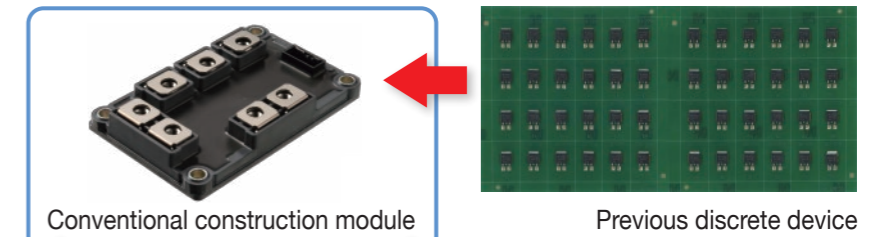
| Type                      | SiC  |   | GaN   |
|---------------------------|--|---|---|
|                           | Half-bridge  | Totem-pole bridgeless PFC   | Half-bridge   |
| Circuit diagram (example) |  |   |   |
| Characteristics (example) | $V_{DSS}=650V$<br>$R_{DS(ON)typ}=20m\Omega, 52m\Omega$ | [SiC MOSFET]<br>$V_{DSS}=650V$<br>$R_{DS(ON)typ}=52m\Omega$<br>[Diode]<br>$V_{RM}=600V$<br>$V_{Ftyp}=0.87V$ | $V_{DSS}=650V$<br>$R_{DS(ON)typ}=50m\Omega$<br>$V_{thtyp}=1.7V$ |

# i-Stack Modules



## Overview

Many modern devices are multifunctional so miniaturization and high heat dissipation are also required for the power module. Shindengen is planning the following single-side and double-side heat dissipation structure modules for compact size and high heat dissipation in a trade-off relationship.



i-Stack module with double-side heat dissipation Heat dissipation from A side DBC board Connector Heat dissipation from B side

Radiation from A surface  
DBC board  
Cu clip  
MOSFET  
DBC board  
Radiation from B surface

- Stack structure reduces mounting area
- Double-sided heat dissipation structure gives high heat dissipation
- Lower internal resistance and inductance

● **Area reduction of about 50%**

● **About 1/3 the weight and volume**

i-Stack module with single-side heat dissipation Cu clip DBC board Heat dissipating side

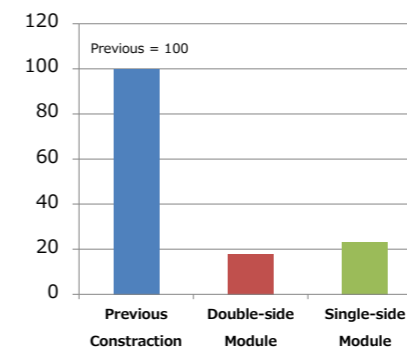
Cu clip  
chip  
chip  
DBC board  
Radiation surface

- Stack structure reduces mounting area
- High heat dissipation by a special laminated structure
- Lower internal resistance and inductance

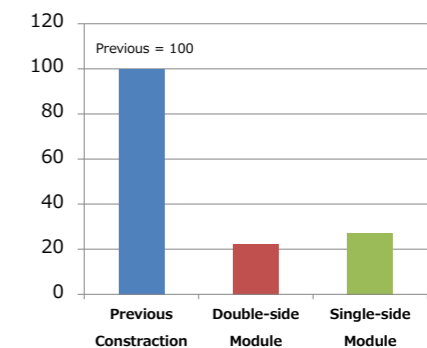
● **Area reduction of about 40%**

● **About 1/3 the weight and volume**

Effect: Wiring Resistance Ratio



Effect: Parasitic Inductance Ratio





Reverse-connection/  
Reverse-current prevention low-loss devices

Under development

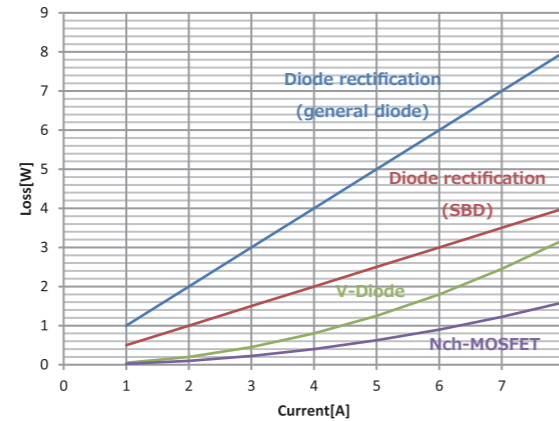
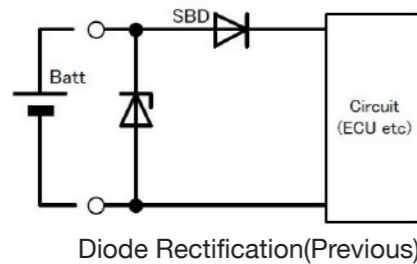
# V-Diode (Pch-MOSFET with reverse-current prevention) High-side Nch-MOSFET gate driver IC



Overview

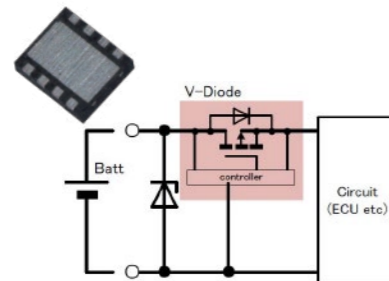
Advances in automotive electronics in recent years, combined with redundancy functions and increased protection functions, has led to increasing power consumption in ECUs. Because of this, the voltage drop and heat generation in the diode to prevent reverse-connection and reverse-current can no longer be ignored. Shindengen proposes a device that reduces the loss at the terminals for reverse-connection and reverse-current prevention in the unit input, and that reduces heat generation and voltage drop.

Features



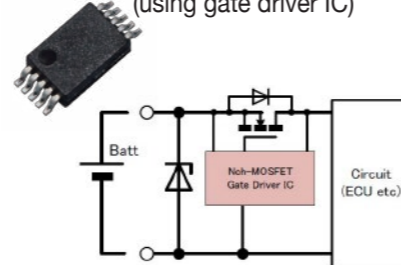
(General Diode: VF=1V, SBD: VF=0.5V, V-Diode: Ron=50mΩ, Nch-MOSFET: Ron=25mΩ)

## V-Diode rectification



Absolute maximum rating: 42V  
Operating voltage: 2.5-40V  
Dark current:  $\leq 3\mu\text{A}$   
Internal reverse-connection/reverse-current prevention  
Internal MOSFET Ron: 50mΩ  
Package: DFN8

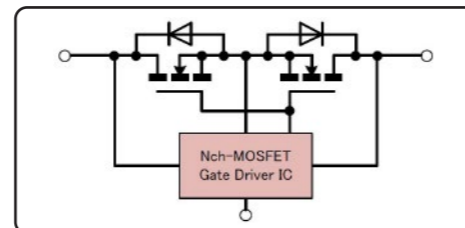
## Nch-MOSFET rectification (using gate driver IC)



Absolute maximum rating: 100V  
Operating voltage: 3.5 - 70V  
Dark current: 3μA (typ.) (with external signal)  
Output current: 100μA (min.)  
Reverse-connection/Reverse-current prevention  
Charge pump: Built-in capacitor (external capacitor available)  
Package: VSOP10

## 【Mechanical Relay Replacement】

This can be used as a driver IC when changing from a mechanical relay to a semiconductor relay.



※V-Diode:Virtual Diode

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